Complementary Silicon Plastic Power Transistors

Specifically designed for power audio output, or high power drivers in audio amplifiers.

- DC Current Gain Specified up to 8.0 A at Temperature
- All On Characteristics at Temperature
- High SOA: 20 A, 18 V, 100 ms
- TO-247AE Package
- Pb-Free Packages are Available*

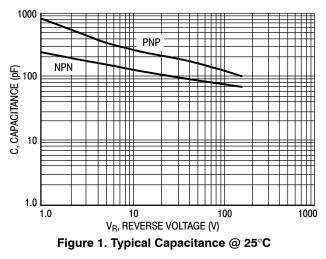
MAXIMUM RATINGS

Rating	Symbol	MJW21191 MJW21192	Unit
Collector-Emitter Voltage	V _{CEO}	150	Vdc
Collector-Base Voltage	V _{CB}	150	Vdc
Emitter-Base Voltage	V _{EB}	5.0	Vdc
Collector Current – Continuous – Peak	Ι _C	8.0 16	Adc
Base Current	I _B	2.0	Adc
Total Power Dissipation @ T _C = 25°C Derate above 25°C	P _D	125 0.65	W W/°C
Operating and Storage Junction Temperature Range	T _J , T _{stg}	−65 to +150	°C

THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction to Case	$R_{\theta JC}$	1.0	°C/W
Thermal Resistance, Junction to Ambient	R _{0JA}	50	°C/W

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.



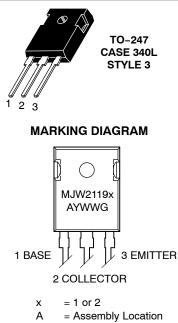
*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.



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8.0 A **POWER TRANSISTORS** COMPLEMENTARY SILICON 150 V, 125 W



= Year

- Y ww = Work Week
- G = Pb-Free Package

ORDERING INFORMATION

Device	Package	Shipping
MJW21191	TO-247	30 Units/Rail
MJW21191G	TO-247 (Pb-Free)	30 Units/Rail
MJW21192	TO-247	30 Units/Rail
MJW21192G	TO–247 (Pb–Free)	30 Units/Rail

ELECTRICAL CHARACTERISTICS (T_C = 25°C unless otherwise noted)

Characteristic	Symbol	Min	Max	Unit
OFF CHARACTERISTICS				
Collector-Emitter Sustaining Voltage (Note 1) $(I_{C} = 10 \text{ mAdc}, I_{B} = 0)$	V _{CEO(sus)}	150	-	Vdc
Collector Cutoff Current (V _{CB} = 250 Vdc, I _E = 0)	ICES	_	10	μAdc
Emitter Cutoff Current ($V_{BE} = 5.0 \text{ Vdc}, I_C = 0$)	I _{EBO}	_	10	μAdc
ON CHARACTERISTICS (Note 1)				
DC Current Gain ($I_C = 4.0 \text{ Adc}, V_{CE} = 2.0 \text{ Vdc}$) ($I_C = 8.0 \text{ Adc}, V_{CE} = 2.0 \text{ Vdc}$)	h _{FE}	15 5.0	100 -	-
Collector-Emitter Saturation Voltage ($I_C = 4.0 \text{ Adc}, I_B = 0.4 \text{ Adc}$) ($I_C = 8.0 \text{ Adc}, I_B = 1.6 \text{ Adc}$)	V _{CE(sat)}		1.0 2.0	Vdc
Base-Emitter On Voltage $(I_C = 4.0 \text{ Adc}, V_{CE} = 2.0 \text{ Vdc})$	V _{BE(on)}	-	2.0	Vdc
DYNAMIC CHARACTERISTICS		-	-	-
Current Gain – Bandwidth Product (Note 2) $(I_C = 1.0 \text{ Adc}, V_{CE} = 10 \text{ Vdc}, f_{test} = 1.0 \text{ MHz})$	f _T	4.0	_	MHz

1. Pulse Test: Pulse Width \leq 300 μ s, Duty Cycle \leq 2.0%.

2. $f_T = |h_{fe}| \bullet f_{test}$.

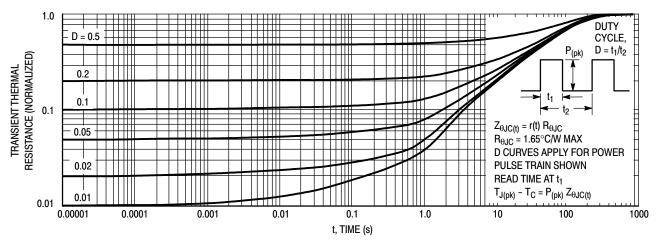
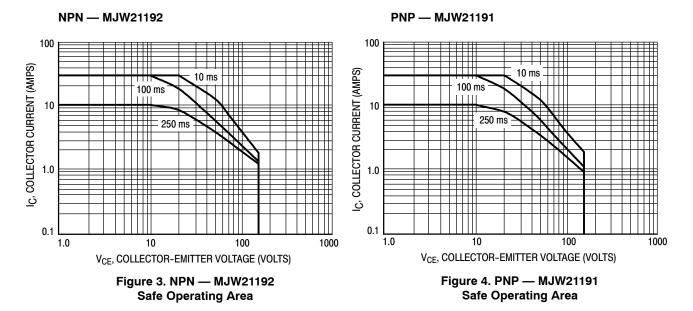


Figure 2. Thermal Response

There are two limitations on the power handling ability of a transistor: average junction temperature and second breakdown. Safe operating area curves indicate $I_C - V_{CE}$ limits of the transistor that must be observed for reliable operation, i.e., the transistor must not be subjected to greater dissipation then the curves indicate.

The data of Figures 3 and 4 is based on $T_{J(pk)} = 150^{\circ}$ C; T_C is variable depending on conditions. Second breakdown pulse limits are valid for duty cycles to 10% provided $T_{J(pk)}$ < 150°C. $T_{J(pk)}$ may be calculated from the data in Figure 2. At high case temperatures, thermal limitations will reduce the power that can be handled to values less than the limitations imposed by second breakdown.



TYPICAL CHARACTERISTICS

NPN — MJW21192

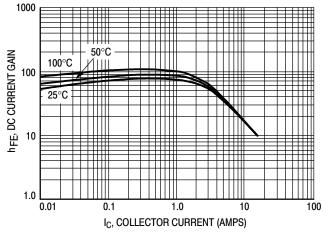


Figure 5. NPN — MJW21192 V_{CE} = 2.0 V DC Current Gain

PNP — MJW21191

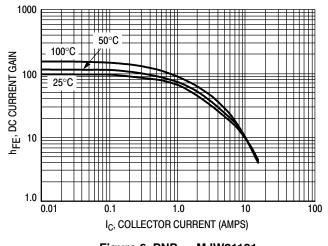
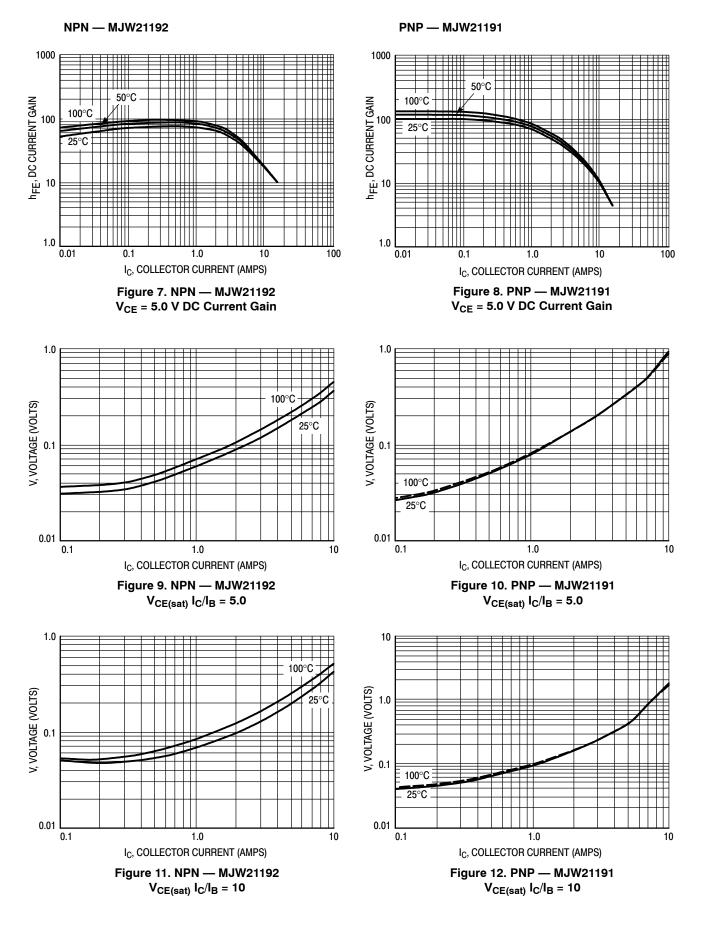
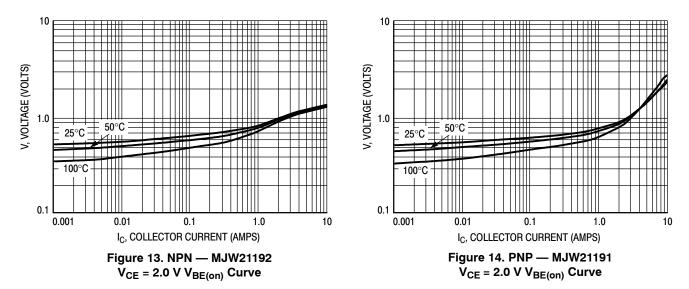


Figure 6. PNP — MJW21191 V_{CE} = 2.0 V DC Current Gain



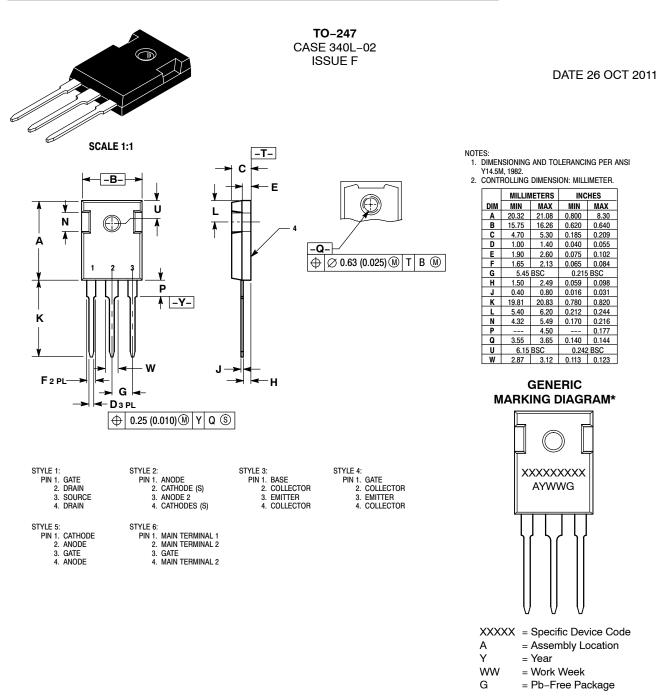
NPN — MJW21192

PNP — MJW21191



MECHANICAL CASE OUTLINE PACKAGE DIMENSIONS





*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot " •", may or may not be present.

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ISSUE	REVISION	DATE	
D	CHANGE OF OWNERSHIP FROM MOTOROLA TO ON SEMICONDUCTOR. DIM A WAS 20.80–21.46/0.819–0.845. DIM K WAS 19.81–20.32/0.780–0.800. UPDATED STYLE 1, ADDED STYLES 2, 3, & 4. REQ. BY L. HAYES.	25 AUG 2000	
E	DIM E MINIMUM WAS 2.20/0.087. DIM K MINIMUM WAS 20.06/0.790. ADDED GENERIC MARKING DIAGRAM. REQ. BY S. ALLEN.	26 FEB 2010	
F	ADDED STYLES 5 AND 6. REQ. BY J. PEREZ.	26 OCT 2011	

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